APPLICATION DATA SHEET

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Application Information

Title : METHOD FOR ENHANCING VERTICAL GROWTH

DURING THE SELECTIVE FORMATION OF SILICON,

AND STRUCTURES FORMED USING SAME

Total Drawing Sheets :

Formal Drawings : YES
Application Type : Utility

Attorney Docket Number : 500803.02

Assigned : Yes (Large Entity)

Representative Information

Representative Customer No. : 27,076

Continuity Information

This application is a : divisional of >Application One : 09/770,909

Filing Date : January 26, 2001

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